

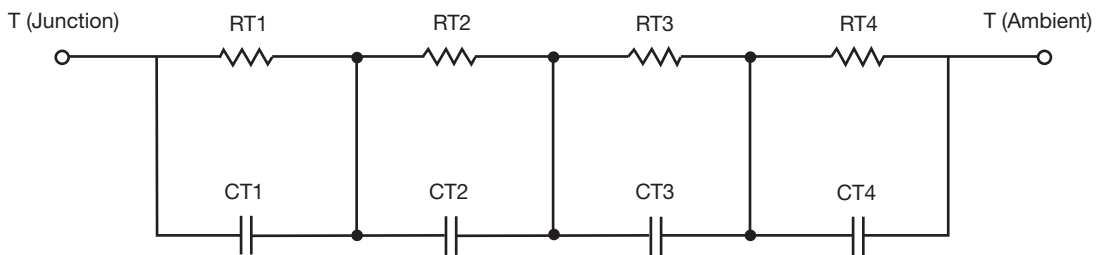
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	20.7613	253.1134m	N/A
RT2	16.1785	110.6522m	N/A
RT3	2.4641	101.2658m	N/A
RT4	624.0134m	35.5338m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	5.4947	213.3406m	N/A
CT2	4.3308	133.1919m	N/A
CT3	686.3164m	46.6453m	N/A
CT4	4.1719m	6.1623m	N/A

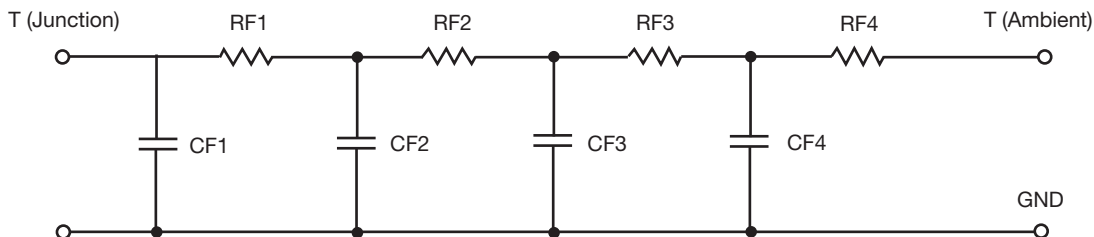
Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	569.6034m	137.9230m	N/A
RF2	1.1588	155.8394m	N/A
RF3	9.7002	115.8873m	N/A
RF4	28.5202	91.5321m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	5.2517m	13.0446m	N/A
CF2	202.7145m	49.0813m	N/A
CF3	1.1307	49.9009m	N/A
CF4	1.8188	502.0781m	N/A

Note

N/A indicates not applicable

